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ABOUT US

GuoHui OPTOelectronic (GHOPTO) is a fabrication and production company dedicated to meet your III/V component and system needs. Our facilities enable wafer based processing and device production capabilities in class 100 to class 100,000 controlled environments. GHOPTO is well known as the first commercial InGaAs imaging manufacturer in China. At GHOPTO domestic and international clients receive full access to unrestricted performance and full supply-chain control: from unprocessed starting material (usually epitaxy) to fully packaged production devices such as IR imagers/cameras, lasers, waveguides and systems.

GHOPTO possesses over 20 years of experience, specifically, in the design, development, and commercialization of imaging technologies such as PIN, QWIP, and other traditional SWIR-MIR-LWIR imaging cores. This is in addition to an expanding new portfolio of emerging research and development into APD and T2SL imaging capabilities.

GHOPTO' s technical team consists of world-renowned experts from China and Canada, with headquarters in Taiyuan, and branch offices in Beijing and Shenzhen.

OUR SERVICE

GHOPTO offers three main modes of business to other companies, universities and institutions: FOUNDRY SERVICES, STANDARD InGaAs IMAGERS, and CUSTOM IR IMAGERS. With each of these modes GHOPTO can provide a tailored spectrum of in-house capabilities from design to production manufacturing that best fits your need.

Standard InGaAs Imagers

Products lines of lattice matched Short-Wave-InfraRed (SWIR) Indium-Gallium-Arsenide (InGaAs) technology. This portfolio includes SWIR and VISIBLE-SWIR linear arrays, focal plane arrays, and cameras.

- Lattice Matched InGaAs Sensor and Camera Production
- 15um Pitch

Foundry Services

1300 square meters of clean rooms (class 100 to class 100,000) dedicated to wafer fabrication, chip packaging and device testing.

- Full Wafer Fabrication (up to 4 inch) and Production
- Device Processing and Chip Packaging
- Characterization

Custom IR Imagers

Custom ROIC and epitaxy integration, new imaging technologies such as APD, and T2SL FPAs.

- ITAR* and ITAR*-free Production Advanced Technologies such as Lattice Mismatched InGaAs, APD, QWIP and T2SL

Standard InGaAs cameras

- Multiple digital signal output interfaces available
USB, GigE, Camera Link

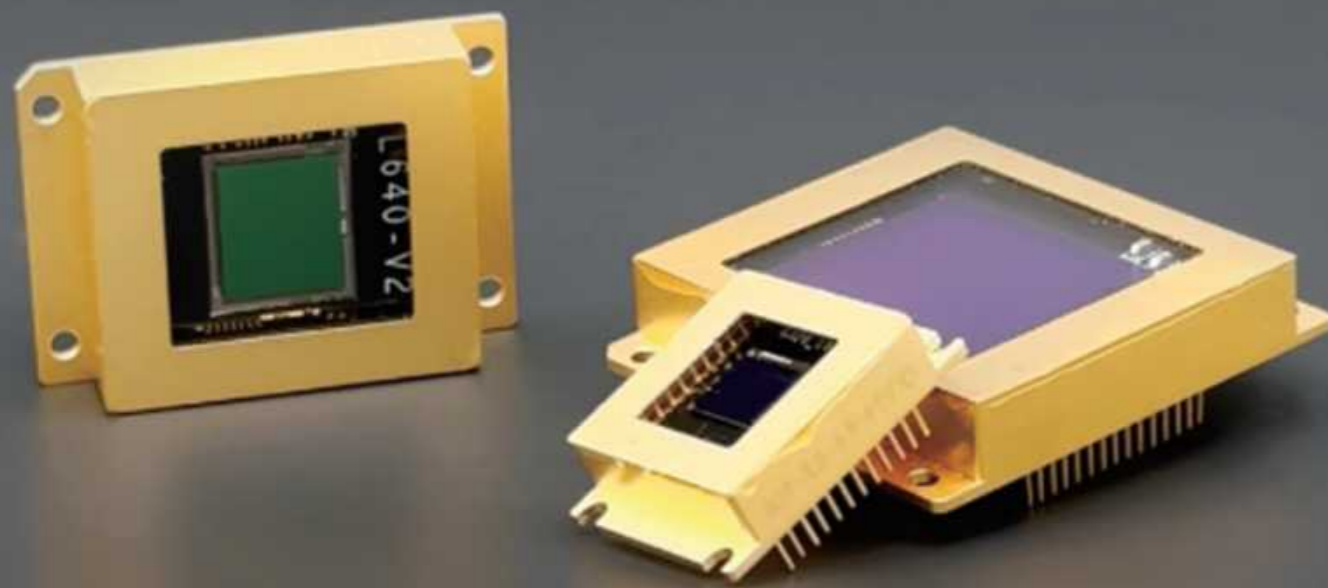
Domestic InGaAs camera solutions

- Completely Self-developed SWIR Camera, Meeting a variety of specific project needs

SWIR LENS

- Various Focal lengths
8mm, 12mm, 25mm, 35mm, 50mm, 75mm, 100mm, 200mm

SWIR SENSORS



→ Basic Specs

SENSOR	GH-SW320	GH-SW640Pro	GH-SW1280
Material	InGaAs	InGaAs	InGaAs
Array Format	320 x 256	640 x 512	1280 x 1024
Pixel Pitch	15µm	15µm	15µm
Spectral Response	0.9µm ~ 1.7µm	0.9µm ~ 1.7µm 0.4µm ~ 1.7µm	0.9µm ~ 1.7µm

→ Key Specs

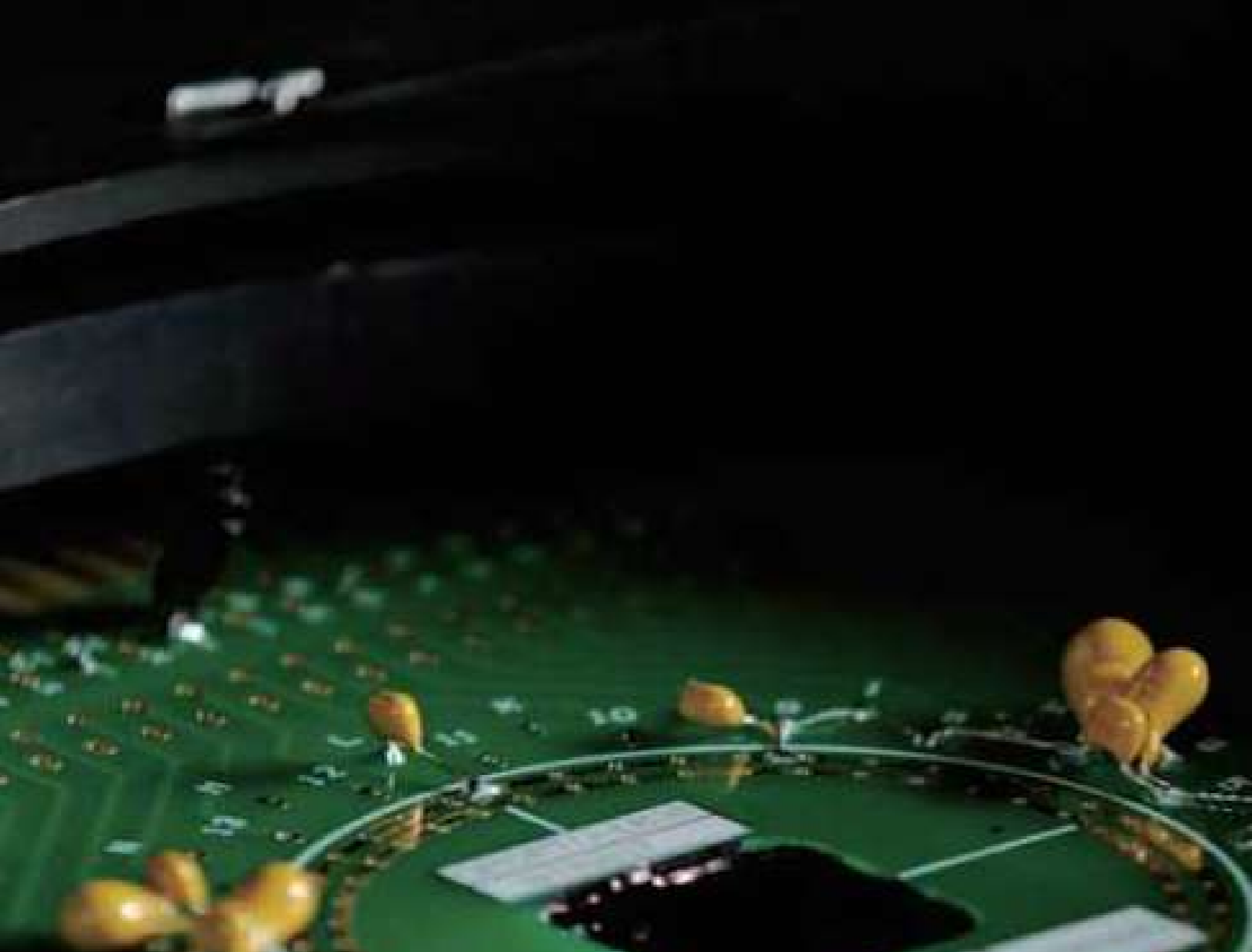
SENSOR	GH-SW320	GH-SW640Pro	GH-SW1280
Quantum Efficiency	>70% (1.0µm ~ 1.6µm)	>70% (1.0µm ~ 1.6µm)	>70% (1.0µm ~ 1.6µm)
Readout Noise	35e- @HG	18e- @HG	40e- @HG
Dark Current	30fA@0.1V&18°C	30fA@0.1V&18°C	30fA@0.1V&18°C
Pixel Operability	> 99.5%(Minimum)	> 99.5%(Minimum)	>99.5%(Minimum)
Non Uniformity	< 5%	< 5%	< 5%

→ ROIC

SENSOR	GH-SW320	GH-SW640Pro	GH-SW1280
Integration Type	Snapshot	Snapshot	Snapshot
Readout Modes	ITR, IWR, CDS	ITR, IWR, CDS	ITR, IWR, CDS
Integration Time	0.2µs to full frame	0.2µs to full frame	0.2µs to full frame
Frame Rate Max	500 Hz	300Hz	100 Hz
Maximum Pixel Rate	18MHz	18MHz	22MHz
Output Swing	≤2V	≤2V	≤2V
Temperature Sensor	Yes	Yes	Yes

→ Package

SENSOR	GH-SW320	GH-SW640Pro	GH-SW1280
Dimensions	24 x 18.5 x 6mm	36 x 25.4 x 7.2mm	40 x 36 x 7.2mm
Window Material	Quartz / sapphire	Quartz/ sapphire	Quartz/ sapphire
No.of Pin	24-pin Metal DIP Package	28-pin Metal DIP Package	30-pin Metal DIP Package
Packaging Type	Hermetically sealed	Hermetically sealed	Hermetically sealed
Operating Temperature	- 40°C ~ 70°C	- 40°C ~ 70°C	- 40°C ~ 70°C
Storage Temperature	- 40°C ~ 70°C	- 40°C ~ 70°C	- 40°C ~ 70°C



SWIR CAMERAS



900-1700nm / 400-1700nm SWIR Cameras

GH-SW640HS-U2	08
GH-SW640HS-Gnet	08
GH-SW640HS-CL	09
GH-SW640Pro-CL2	10
GH-SW640Pro-GigE	10
GH-SW640Pro-U3	11
GH-SW320-U2	12
GH-SW320-Gnet	12







400-1700nm SWIR Cameras

GH-SW033-U3	13
GH-SW130-U3	13
GH-SW033-GigE	14
GH-SW130-GigE	14

900-1700nm / 400-1700nm SWIR Cameras

GH-SW640HS-U2
GH-SW640HS-Gnet



- 
640x512
- 
15μm
- 
TEC 1
- 
900-1700nm / 400-1700nm
- 
USB2.0 / Gnet
- 
Global shutter
Single point Correction

Basic Specs	Model Type	GH-SW640HS-U2	GH-SW640HS-Gnet
Frame Rate		50Hz	100Hz
Integration Time		100μs ~ 20ms	100 μs ~ 20ms / Max 9ms at 100Hz
Digital Output		USB 2.0	Gnet
Trigger		/	RS-422 / TTL

Key Specs	Sensor	GH-SW640HS
Resolution		640 x 512
Spectral Response		900 ~ 1700nm / 400 ~ 1700nm
Pixel Pitch		15μm
Active Area		9.6mm x 7.68mm
Quantum Efficiency		> 70% (1.0 μm~ 1.6μm)
Integration Type		snapshot
Pixel Capacity		> 99.5%
Full Well Capacity		1.8Me-
ADC		14bit
Analog Video Output		PAL、SMA Interface
Software		Windows Software/windows SDK
Power Input		DC 12V ± 2V
Power Dissipation		< 4W (TEC OFF)
Dimensions		65mm × 58mm × 75mm (without Lens)
Lens Mount		C-Mount
Operating Temp		-20 °C ~ +50 °C / -40 °C ~ +70 °C (Optional)
Storage Temp		-40 °C ~ +80 °C
On-Board Image Processing		Single/two-point correction, bad pixel replacement, image denoising, image smoothing, controllable shutter compensation

* Technical data are subject to change without notice

900-1700nm / 400-1700nm SWIR Cameras

GH-SW640HS-CL



- 640x512
- 15µm
- TEC 1
- 900-1700nm / 400-1700nm
- CameraLink
- Global shutter
Single point Correction

Model type	GH-SW640HS-CL
Sensor	GH-SW640HS
Resolution	640 x 512
Spectral Response	900 ~ 1700nm / 400 ~ 1700nm
Pixel Pitch	15µm
Active Area	9.6mm x 7.68mm
Quantum Efficiency	> 70 % (1.0 µm ~ 1.6µm)
Frame Rate	100Hz / 200 Hz (Optional)
Integration Type	snapshot
Integration Time	100µs ~ 20ms / Max 9ms at 100Hz
Pixel Capacity	> 99.5%
Full Well Capacity	1.8Me-
ADC	14bit
Analog Video Output	PAL, SMA Interface
Digital Output	SDR 26 pin connector, Base Camera Link
Software	Windows Software/windows SDK
Trigger	Camera link Via Camera Link CC1 (Delay < 1µs)
Mode Control	Camera Link SerTC, SerTFG. Baud: 115200 bps
Power Input	DC 12V ± 2V
Power Dissipation	< 3W (TEC OFF)
Dimensions	61mm × 62mm × 59mm (without Lens)
Lens Mount	C-Mount
Operating Temp	-20 °C~ +50 °C / -40 °C~ + 70 °C (Optional)
Storage Temp	-40 °C ~ + 80 °C
On-Board Image Processing	Single/two-point correction, bad pixel replacement, image denoising, image smoothing, controllable shutter compensation

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900-1700nm / 400-1700nm SWIR Cameras

GH-SW640Pro-CL2

GH-SW640Pro-GigE

- 640x512
- 15µm
- Global shutter
- SDK
- 700fps
- 900-1700nm / 400-1700nm
- Dual CameraLink Interface
GigE
- TE Cooler
The cooling temperature is 40 degrees below the ambient temperature

Basic Specs	Model Type	GH-SW640Pro-GigE	GH-SW640Pro-CL2	
Frame rate		125Hz	500Hz	700Hz
Integration Time		50µs ~ 5s	31.25µs ~ 1.7ms	23.81µs ~ 1.3ms
Interface		GigE	Dual CameraLink Interface	
Software		SDK	SDK supporting CameraLink capture card	

Key Specs	Sensor	GH-SW640Pro
Resolution		640 x 512
Spectral Response		900 ~ 1700nm / 400 ~ 1700nm
Pixel pitch		15µm
Lens mount		C-Mount
Quantum efficiency		> 70% (1.0µm ~ 1.6µm)
Full well capacity		1.8Me-
ADC		8bit / 14bit
Cooling		TEC
Dark current		30fA@0.1V&18°C
Interface		Dual CameraLink Interface
Exposure mode		Global exposure
Readout mode		IWR
Power Input		DC 12V
Power consumption		< 10W
Weight		≤500g (without Lens)
Dimensions		68mm x 68mm x 89.1mm (without Lens)
Operating Temp		-20 °C ~ +60 °C
Storage Temp		-40 °C ~ + 85 °C

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900-1700nm / 400-1700nm SWIR Cameras

GH-SW640Pro-U3



640x512	15µm	TEC
USB3.0	SDK	400fps
900-1700nm / 400-1700nm		
Global shutter Single point Correction		

Model Type	GH-SW640Pro-U3		
Sensor	GH-SW640Pro		
Shutter Mode	Global Shutter		
Active Area	9.6mm x 7.2mm		
Resolution	640 x 512		
Pixel Pitch	15µm		
Frame Rate	400Hz		
Integration Time	40µs ~ 1s		
Pixel format	Mono		
Spectral Response	900 ~ 1700nm / 400 ~ 1700nm		
Dynamic Range	69.8dB		
SNR	62.42dB		
Pixel Bit Depth	8/14 bit		
Power Input	12V DC, 4.8W (TEC Off)		
Cooling Method	TEC		
Dimension(L x W x H)	55mm x 55mm x 60mm		
Lens Mount	C-Mount		
Operating Temp.	-40 C ~ +60 C		
Weight	<250g		
Certificate	CE、 FCC、 RoHS		
Dark Current	HG: 26.5e	MG: 42.8e	LG: 400e
Full Well Capacity	HG: 8.5Ke	MG: 63.9Ke	LG: 1.5Me
Data Interface	USB3.0		

* Technical data are subject to change without notice

900-1700nm / 400-1700nm SWIR Cameras

GH-SW320-U2 GH-SW320-Gnet



320x256	15µm	400fps
900-1700nm / 400-1700nm	USB 2.0 /Gnet	TEC
Global shutter Single point Correction		

Basic Specs	Model Type	GH-SW320-U2	GH-SW320-Gnet
Frame rate		200Hz	400Hz
Integration Time		100 µs ~ 20 ms Max 4.5ms at 200Hz	100 µs ~ 20ms Max 2ms at 400Hz
Interface		USB 2.0	Gnet

Key Specs	Sensor	GH-SW320
Resolution		320 x 256
Spectral Response		900 ~ 1700nm / 400 ~ 1700nm
Pixel pitch		15µm
Lens mount		C - Mount
Quantum Efficiency		> 70% (1.0µm ~ 1.6µm)
Full Well Capacity		2.2Me-
ADC		14bit
Cooling		TEC
Dark Current		30fA@0.1V&18°C
Software		Windows Software/windows SDK
Trigger		RS-422 / TTL
Exposure Mode		Global exposure
Readout mode		IWR
Power Input		DC 12V ± 2V
Power consumption		< 4W (TEC off)
Weight		200g (No lens)
Dimensions		55mm x 50mm x 63mm (No lens)
Operating Temp		-20 °C ~ +50 °C / -40 °C ~ + 70 °C (Optional)
Storage Temp		-40 °C ~ + 80 °C
On-board Image Processing		Single/two-point correction, bad pixel replacement, image denoising, image smoothing, controllable shutter compensation

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400-1700nm SWIR Cameras

GH-SW033-U3
GH-SW130-U3



TE Cooler
The cooling temperature is 40 degrees below the ambient temperature

Basic Specs	Model type	GH-SW033-U3	GH-SW130-U3
	Sensor	Sony IMX991	
Resolution	640 x 512		1280 x 1024
Active area	3.2mm x 2.56mm		6.4mm x 5.12mm
Frame rate	137fps@640 x 512 258fps@320 x 256	257.8fps@640 x 512 486.1fps@320 x 256	70fps@1280 x 1024 135fps@640 x 512
ADC	12bit	8bit	12bit 8bit
Conversion gain	42.29e-/ADU		44.3e-/ADU
Dynamic range	59.7dB		58.7dB
Readout noise	174.99e-		211e-
Full well charge	173.23ke-		181.6ke-
Max SNR	52.39dB		52.6dB
Dark current	172.39e-/s		383e-/s(0°C) 510e-/s(10°C) 638e-/s(20°C)
Cooling temp	25°C below ambient temperature		25 ~ 30°C below ambient temperature

Key Specs	Spectral range	400 ~ 1700nm	Pixel format	Mono8 / Mono12
	Pixel pitch	5µm	Power consumption	<2.1W (uncooled) / <25W (cooled)
DDR3	512MB (4Gb)	Humidity	20% ~ 80% No Condensation	
Sensitivity	121mV	Filter	400-1800nm (Standard) / 1030-1800nm (Optional)	
Exposure time range	50µs ~ 60s	Dimensions	80mm x 80mm x 45.5mm	
Gain range	1x ~ 15x	Lens mount	C-Mount	
Shutter mode	Global Shutter	Software	SDK/ ToupView	
Binning	Software 2x2, 3x3, 4x4	Weight	384.1g	
Data interface	USB3.0	Certificate	CE, FCC	
Operating system	Win32/ WinRT/ Linux/ macOS/ Android			
Power supply	USB3.0 interface power supply / 12V power adapter power supply			
Digital I/O	1 optical-coupling isolated input, 1 optical-coupling isolated output, 2 non-isolated input and output			
Temperature	Operating Temp -20°C~ 60°C ,Storage Temp -40°C~ 85°C			

* Technical data are subject to change without notice

400-1700nm SWIR Cameras

GH-SW033-GigE
GH-SW130-GigE



Basic Specs	Model type	GH-SW033-GigE	GH-SW130-GigE
	Sensor	Sony InGaAs CMOS IMX 991	
Resolution	640 x 512		1280 x 1024
Image size	3.2mm x 2.56mm		6.4mm x 5.12mm
Max frame rate	258Hz		90Hz

Key Specs	Spectral range	400 ~ 1700nm	Pixel format	Mono 8/12
	Pixel pitch	5µm	Binning	2x2 supported
Gain	24Times	Frame buffer	256M Bytes	
Dynamic range	90DB	User parameter area	4K Bytes	
Exposure time	0.013ms ~ 133ms	IP rating	IP30	
Pixel depth	8/12bit	Data interface	GigE @ 1Gbps	
Digital I/O	6 pin connectors for power supply, I/O: 1 optical-coupling isolated input, 2 optical-coupling isolated output			
Power supply	Default 12V DC, PoE Supported (USB3.0, 5V DC optional)			
Power consumption	<3.5W @5V DC (USB for power supply) / < 3.0W @12V DC			
Lens mount	C-mount / CS-mount			
Collection method	Continuous / soft trigger / hard trigger			
Temperature	Operating Temp 0°C~ 50°C / Storage Temp -30°C~ 70°C			
Humidity	20% ~ 80% RH No Condensation			
Driver	DirectShow / Twain / Halcon / OCX supported			
Software supported	Compatible with Halcon / OpenCV / LabView / Matlab			
Programmable language	C/C++ / VB6 / VB.net / Delphi6 / C# / QT / C++Builder / LabView /Python			
Operating system	Windows / Linux / Android / MacOS			
Protocol	GigE Vision V1.2			

* Technical data are subject to change without notice

SWIR Lens



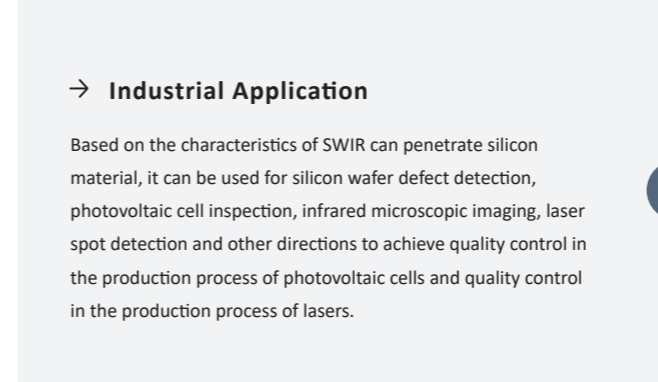
SWIR Lens	Focal Length	F/#	Mount	Working Wavelength	Weight
700-1700nm SWIR Lens	25 mm	1.4	C-Mount	700-1700nm	< 200g
700-1700nm SWIR Lens	35 mm	1.4	C-Mount	700-1700nm	189g
800-1700nm SWIR Lens	8 mm	1.4	C-Mount	800-1700nm	< 200g
800-1700nm SWIR Lens	12 mm	1.4	C-Mount	800-1700nm	< 260g
800-1700nm SWIR Lens	40 mm	1.4	C-Mount	800-1700nm	370
800-1800nm SWIR Lens	50 mm	2.15	C-Mount	800-1800nm	250g
800-1800nm SWIR Lens	25 mm	2.1	C-Mount	800-1800nm	/
800-1800nm SWIR Lens	100 mm	2.1	C-Mount	800-1800nm	/
900-1700nm SWIR Lens	200 mm	2.4	/	900-1700nm	/

APPLICATIONS



← Aerospace Applications

Based on the characteristics of the high spectral response of SWIR devices to the 1.3 μ m and 1.5 μ m of communication lasers, it can be applied to satellites, UAVs, and aircraft as optoelectronic payloads to achieve interplanetary communication, remote sensing detection, atmospheric composition analysis, geological exploration, etc.



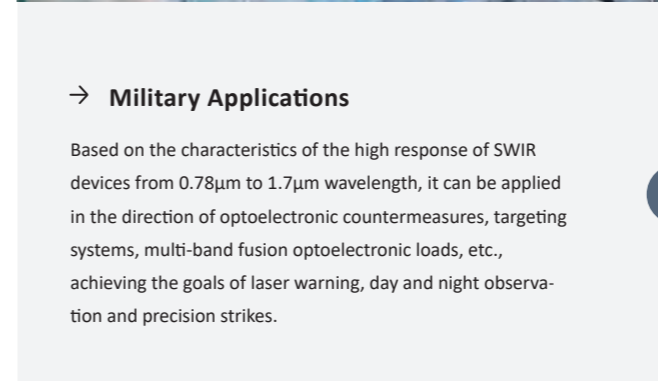
→ Industrial Application

Based on the characteristics of SWIR can penetrate silicon material, it can be used for silicon wafer defect detection, photovoltaic cell inspection, infrared microscopic imaging, laser spot detection and other directions to achieve quality control in the production process of photovoltaic cells and quality control in the production process of lasers.



← Spectral Application

Based on the characteristics of the spectrum of different materials in SWIR, it can be applied in the direction of spectral sorting, plant moisture condition monitoring, and mineral type identification to achieve fine sorting of agricultural and food crops, plastic solid waste classification, and recycling, crop precision irrigation, mineral distribution exploration, etc.



→ Military Applications

Based on the characteristics of the high response of SWIR devices from 0.78 μ m to 1.7 μ m wavelength, it can be applied in the direction of optoelectronic countermeasures, targeting systems, multi-band fusion optoelectronic loads, etc., achieving the goals of laser warning, day and night observation and precision strikes.

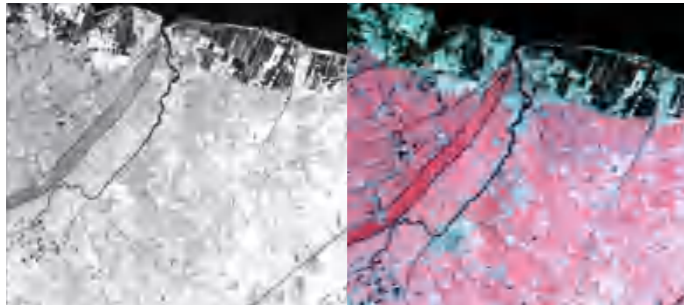
APPLICATIONS



APPLICATION | Border Defense



APPLICATION | Agricultural Inspection



APPLICATION | Remote-Sensing Multispectral Imaging



APPLICATION | Non-invasive Inspection of Cultural Relics



APPLICATION | Semiconductor Inspection



APPLICATION | Industrial Inspection

Find out more



▶ SWIR Camera—Fog



▶ SWIR Camera—Haze



▶ SWIR Camera—Smoke